

Initial Release

16 Channel High Voltage Analog Switch with Bleed Resistors

Features

- □ HVCMOS technology for high performance
- 220V operating conditions
- Output On-resistance typically 22Ω
- ☐ Integrated bleed resistors on the outputs
- □ 5.0V and 12.0V CMOS logic compatibility
- Uery low quiescent power dissipation -10μA
- □ -45dB min off isolation at 7.5MHz
- Low parasitic capacitance
- Excellent noise immunity
- □ Flexible operating supply voltages

Applications

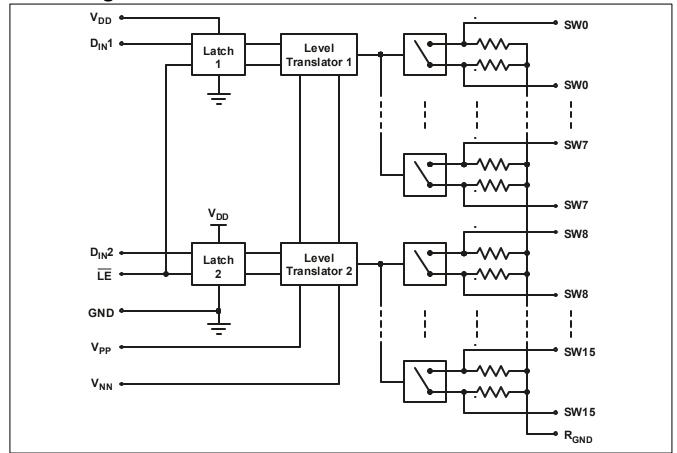
- Medical ultrasound imaging
- ☐ Piezoelectric transducer drivers

Description

The Supertex HV238 is a 220V 16-channel high voltage analog switch integrated circuit (IC) with output bleed resistors ($R_{\rm INT}$). The output switches are configured as 2 sets of 8 single pole single throw analog switches. It is intended to be used in applications requiring high voltage switching controlled by low voltage control signals such as ultrasound imaging.

The 2 sets of 8 analog switches are controlled by 2 input logic controls, $D_{\rm IN}1$ and $D_{\rm IN}2$. A logic high on $D_{\rm IN}1$ will turn ON switches 0 to 7 and a logic high on $D_{\rm IN}2$ will turn ON switches 8 to 15. The bleed resistors help significantly reduce voltage built up on capacitive loads such as piezoelectric transducers connected to the outputs.

Block Diagram



Rev. 2

Nov. 26, 2003

Ordering Information

Device	Package Options				
Device	48 Lead TQFP				
HV238	HV238FG				

Absolute Maximum Ratings*

V _{DD} Logic supply	-0.5V to +15V
V _{PP} -V _{NN} differential supply	225V
V _{PP} Positive supply	-0.5V to V _{NN} +225V
V _{NN} Negative supply	+0.5V to -225V
Logic input voltage	-0.5V to V _{DD} +0.3V
Analog signal range	V_{NN} to V_{PP}
Peak analog signal current/channel	3.0A
Storage temperature	-65°C to 150°C
Power dissipation	48 lead TQFP 1.0W

^{*}Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability.

Operating Conditions*

Symbol	Parameter	Value							
V _{PP}	Positive high voltage supply	50V to 110V							
V _{NN}	Negative high voltage supply	-10V to V _{PP} –220V							
V _{DD}	Logic power supply voltage	4.75V to 12.6V							
V _{IH}	High level input voltage	V_{DD} -1.0V to V_{DD}							
V _{IL}	Low level input voltage	0V to 1.0V							
V _{SIG}	Analog signal voltage peak-to-peak	V _{NN} +10V to V _{PP} -10V							
T _A	Operating free air temperature	0°C to 70°C							

^{*} Notes:

Truth Table

D _{IN} 2	D _{IN} 1	LE bar	SW0 to SW7	SW8 to SW15
L	L	L	OFF	OFF
L	Н	L	ON	OFF
Н	L	L	OFF	ON
Н	Н	L	ON	ON
Х	Х	Н	Hold Prev	ious State

¹ Power up/down sequence is arbitrary except GND must be powered-up first and powered-down last.

² V_{SIG} must be within V_{NN} and V_{PP} or floating during power up/down transition.

³ Rise and fall times of power supplies V_{DD}, V_{DD}, and V_M, should not be less than 1.0msec.

Electrical Characteristics

DC Characteristics (over recommended operating conditions unless otherwise noted)

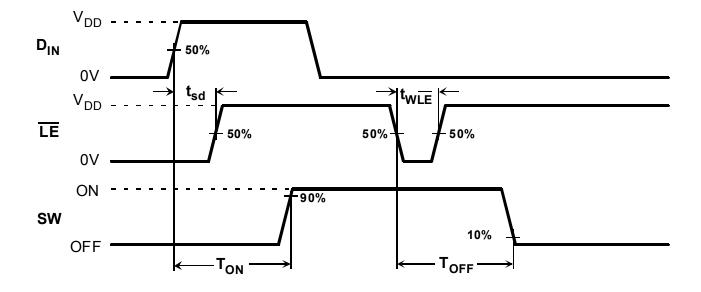
Svm	Parameter	0°C +25°C					+70°C		Units	T ,
Sym	Parameter	Min	Max	Min	Тур	Max	Min	Max	Units	Conditions
			30		26	32		40		V_{SIG} =0V, I_{SIG} =5mA, V_{PP} =50V, V_{NN} =-170V V_{SIG} =0V, I_{SIG} =200mA,
R _{ons}	Small Signal Switch		25		22	27		35	Ω	V _{SIG} =0V, I _{SIG} =200mA, V _{PP} =50V, V _{NN} =-170V V _{SIG} =0V, I _{SIG} =5mA,
0143	On-Resistance		15		22	27		30		V _{SIG} =0V, I _{SIG} =5mA, V _{PP} =110V, V _{NN} =-110V V _{SIG} =0V, I _{SIG} =200mA,
			20		18	22		25		V _{SIG} =0V, I _{SIG} =200mA, V _{PP} =110V, V _{NN} =-110V
$\Delta R_{ m ons}$	Small Signal Switch On-Resistance Matching		20		5.0	20		20	%	V _{SIG} =0V, I _{SIG} =5mA, V _{PP} =110V, V _{NN} =-110V
R _{ONL}	Large Signal Switch On-Resistance				15				Ω	V _{SIG} =0V, I _{SIG} =1.0A
R _{INT}	Output Switch Shunt Resistance			20	35	50			ΚΩ	Output Switch to R _{GND} I _{RINT} = 0.5mA
I _{SOL}	Switch Off Leakage per Switch		5.0		1.0	10		15	μΑ	$V_{SIG} = V_{PP}$ -10V and $V_{NN} = +10V$
	DC offset Switch off		300		100	300		300	mV	No Load
	DC offset Switch on		500		100	500		500	mV	No Load
I _{PPQ}	Quiescent V _{PP} supply current				10	50			μA	All switches off
I _{NNQ}	Quiescent V _{NN} supply current				-10	-50			μΑ	All switches off
I _{PPQ}	Quiescent V _{PP} supply current				10	50			μΑ	All switches on, I _{sw} =5mA
I _{NNQ}	Quiescent V _{NN} supply current				-10	-50			μΑ	All switches on, I _{sw} =5mA
	Switch output peak current		3.0		3.0	2.0		2.0	А	V _{SIG} duty cycle < 0.1%
f _{sw}	Output switch frequency					50			kHz	Duty cycle=50%
I _{PP}	Average V _{PP} supply current		6.5			8.8		10	mA	V _{PP} =50V, V _{NN} =-170V, All Switches turning ON and
I _{NN}	Average V _{NN} supply current		8.1			-8.8		-10		OFF at 50kHz
I _{PP}	Average V _{PP} supply current		-8.1			6.3		6.9	mA Sw	V _{PP} =110V, V _{NN} =-110V, All Switches turning ON and
I _{NN}	Average V _{NN} supply current		5.0			-6.3		-6.9		OFF at 50kHz
I _{DDQ}	Quiescent V _{DD} supply current		10			10		10	μA	All logic inputs are static
I _{DD}	Average V _{DD} supply current		2.0			2.0		2.0	mA	D _{IN} 1= D _{IN} 2=3MHz, LE bar =high
C _{IN}	Logic input capacitance		10			10		10	pF	

Electrical Characteristics

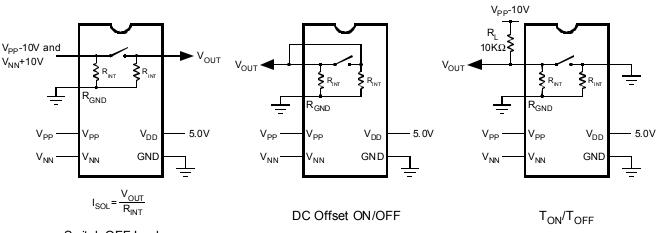
AC Characteristics (over recommended operating conditions unless otherwise noted)

0	Parameter	0°C		+25°C			+70°C		I Imita	0
Sym		Min	Max	Min	Тур	Max	Min	Max	Units	Conditions
t _{WLE}	Time Width of LE bar	150		150			150		ns	
t_{WDIN}	Time Width of D _{IN}	150		150			150		ns	
t _{SD}	Set Up Time Before LE bar Rises	150		150			150		ns	
T _{ON}	Turn On Time		2.0			2.0		2.0	μs	$V_{SIG}=V_{PP}$ -10V, R _{LOAD} =10K Ω
T _{OFF}	Turn Off Time		2.0			2.0		2.0	μs	$V_{SIG}=V_{PP}-10V,$ $R_{LOAD}=10K\Omega$
dv/dt	Maximum Vsig Slew Rate		20			20		20	V/ns	
КО	Off Isolation	-30		-30	-33		-30		dB	f=5MHz, Load=1KΩ//15pF
		-45		-45	-50		-45			f=7.5MHz, R_{LOAD} =50 Ω
K _{CR}	Switch Crosstalk	-45		-45			-45		dB	f=5.0MHz, R $_{LOAD}$ =50 Ω
I _{ID}	Output Switch Isolation Diode Current		300			300		300	mA	300ns pulse width, 2.0% duty cycle
C _{SG(OFF)}	Off Capacitance Switch to Gnd	5.0	17	5.0	12	17	5.0	17	pF	V _{SIG} =0V, f=1.0MHz
C _{SG(ON)}	On Capacitance Swithc to Gnd	25	50	25	38	50	25	50	pF	V _{SIG} =0V, f=1.0MHz
+V _{SPK}	Output Voltage				4.0				V R	D 500
-V _{SPK}	Spike				-4.0				V	R_{LOAD} =50 Ω

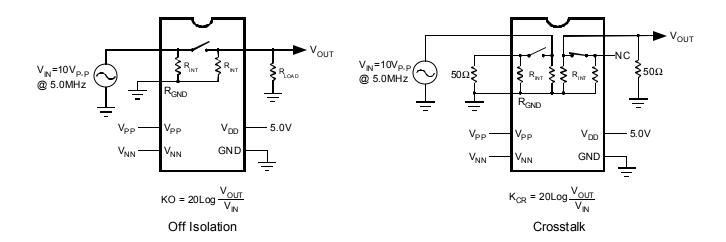
Logic Timing Diagram

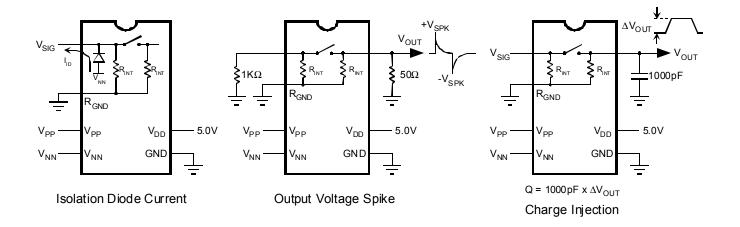


Test Circuits



Switch OFF Leakage



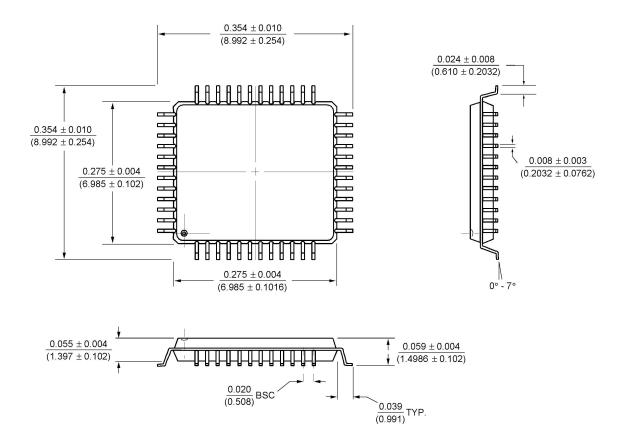


Pin Configurations

48 Lead TQFP

Pin	Function	Pin	Function	
1	V _{NN}	25	SW10	
2	N/C	26	SW10	40 27
3	V _{PP}	27	SW9	48 37
4	N/C	28	SW9	
5	D _{IN} 1	29	SW8	T
6	LE bar	30	SW8	1 □ □ 36
7	D _{IN} 2	31	SW7	
8	N/C	32	SW7	
9	N/C	33	SW6	
10	V_{DD}	34	SW6	48 Lead TQFP 🗮
11	GND	35	SW5	
12	N/C	36	SW5	top view)
13	R _{GND}	37	SW4	
14	SW15	38	N/C	
15	SW15	39	SW4	
16	SW14	40	N/C	12 - 25
17	SW14	41	SW3	T
18	SW13	42	SW3	
19	SW13	43	SW2	13 24
20	SW12	44	SW2	
21	SW12	45	SW1	
22	SW11	46	SW1	
23	SW11	47	SW0	
24	N/C	48	SW0	

48-Lead TQFP Package Dimension



Measurement Legend = Dimensions in Inches (Dimensions in Millimeters)

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